



DMPH4015SSSQ

Product Summary

BV _{DSS}	BV _{DSS} R _{DS(ON) Max} I _C T _A = +	
-40V	11mΩ @ V _{GS} = -10V	-11.4A
	15mΩ @ V _{GS} = -4.5V	-9.8A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP, and is ideal for use in:

- DC-DC Converters
- Power Management Functions
- Analog Switch

Features and Benefits

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switch (UIS) Test in Production Low On-Resistance

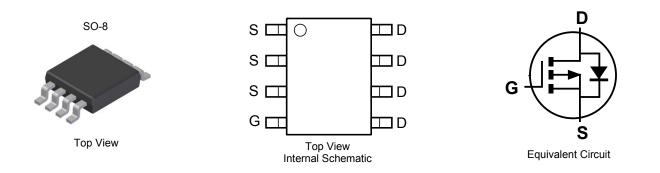
P-CHANNEL ENHANCEMENT MODE MOSFET

- Low Input Capacitance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMPH4015SSSQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Lead-Frame. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.074 grams (Approximate)



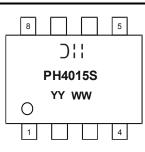
Ordering Information (Note 4)

Part Number	Case	Packaging
DMPH4015SSSQ-13	SO-8	2,500/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



)¦¦ = Manufacturer's Marking PH4015S = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 18 = 2018) WW = Week (01 to 53)



Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	-40	V
Gate-Source Voltage			V _{GSS}	±25	V
Continuous Drain Current (Note 6) V_{GS} = -10V	Steady State	T _A = +25°C T _A = +100°C	ID	-11.4 -8.1	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	()		I _{DM}	-85	A
Maximum Body Diode Continuous Current (Note 6)			Is	-3	A
Avalanche Current L = 1mH			I _{AS}	-22	A
Avalanche Energy L = 1mH			E _{AS}	260	mJ

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	1.4	W
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	90	°C/W
Total Power Dissipation (Note 6)	PD	1.8	W
Thermal Resistance, Junction to Ambient (Note 6)	R _{θJA}	70	°C/W
Thermal Resistance, Junction to Case (Note 6)	Rejc	7.0	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +175	°C

Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	-40	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	-1	μA	V _{DS} = -40V, V _{GS} = 0V	
Gate-Source Leakage	IGSS	_	_	±100	nA	$V_{GS} = \pm 25V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	-1.5	_	-2.5	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$	
Static Drain-Source On-Resistance	D		9	11	mΩ	V _{GS} = -10V, I _D = -9.8A	
	R _{DS(ON)}	_	11	15	11152	V _{GS} = -4.5V, I _D = -9.8A	
Forward Transfer Admittance	Y _{fs}		26	_	S	V _{DS} = -20V, I _D = -9.8A	
Diode Forward Voltage	V _{SD}	_	-0.7	-1	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	4,234	_		V _{DS} = -20V, V _{GS} = 0V f = 1MHz	
Output Capacitance	Coss	_	1,036	_	pF		
Reverse Transfer Capacitance	Crss	_	526	_			
Gate Resistance	R _G	_	7.8	_	Ω	V _{DS} = 0V, V _{GS} = 0V, f = 1MHz	
Total Gate Charge (V _{GS} = -4.5V)	Qg		42.7	_			
Total Gate Charge (V _{GS} = -10V)	Qg	_	91	_	nC	V _{DS} = -20V, I _D = -9.8A	
Gate-Source Charge	Q _{gs}	_	14.2	_			
Gate-Drain Charge	Q _{gd}	_	13.5	_			
Turn-On Delay Time	t _{D(ON)}	_	13.2	_			
Turn-On Rise Time	t _R	_	10	_		$V_{GS} = -10V, V_{DD} = -20V, R_G = 6\Omega,$ $I_D = -1A, R_L = 20\Omega$	
Turn-Off Delay Time	t _{D(OFF)}	_	303	_	ns		
Turn-Off Fall Time	t _F	_	138	—	1		
Reverse Recovery Time	t _{RR}		26	—	ns	I _F = -9.8A, di/dt = -100A/µs	
Reverse Recovery Charge	Q _{RR}		20	—	nC	I _F = -9.8A, di/dt = -100A/µs	

Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

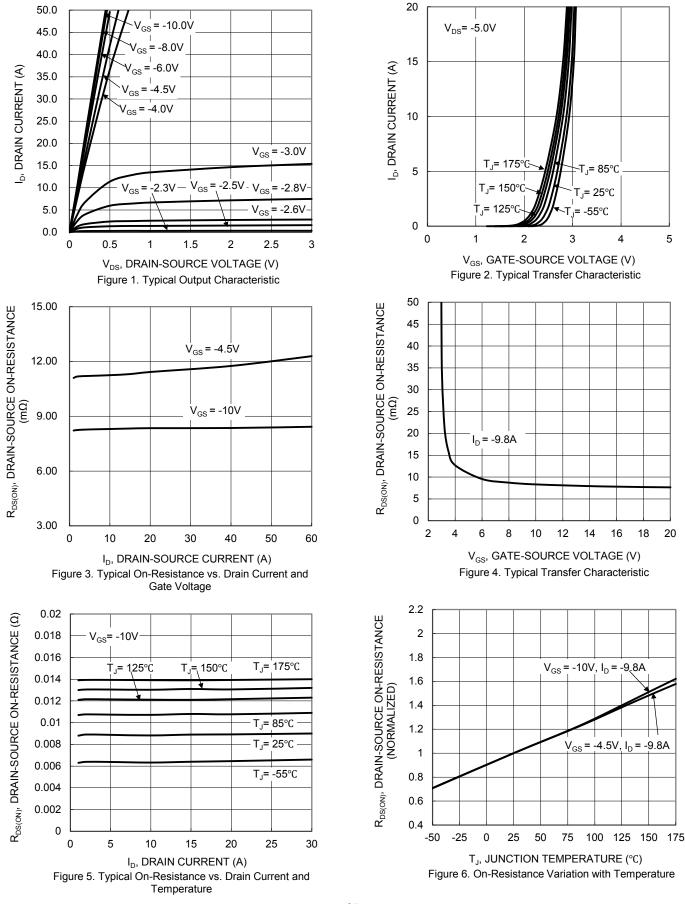
6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.



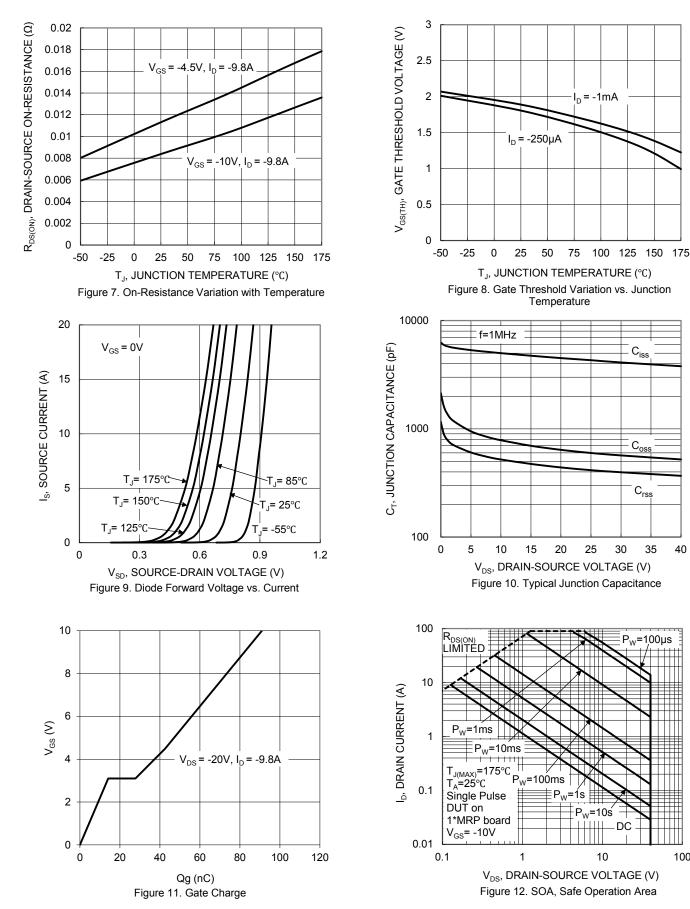
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DMPH4015SSSQ Document number: DS39086 Rev. 3 - 2



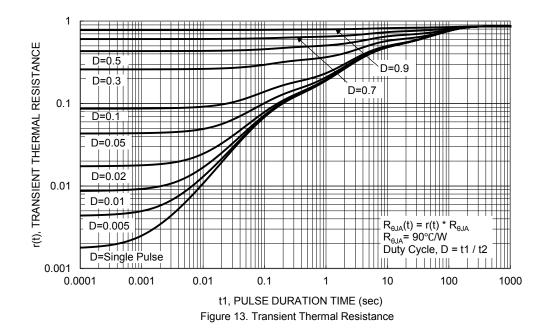
DMPH4015SSSQ



100

40







SO-8

Max

1.50

0.20

0.50

0.25

4.95

6.10

3.90

3.95

0.82

0.70

Тур

1.45

0.15

0.40 0.20

4.90

6.00

3.85

3.90

1.27

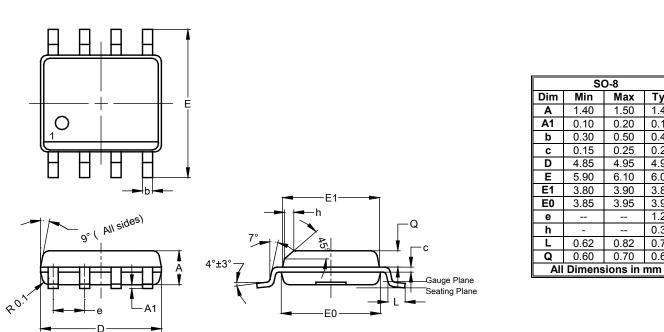
0.35

0.72

0.65

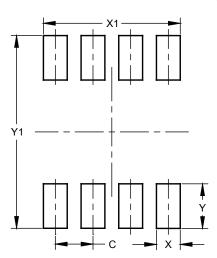
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



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SO-8

Dimensions	Value (in mm)			
С	1.27			
Х	0.802			
X1	4.612			
Y	1.505			
Y1	6.50			

SO-8



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